

#### **Multi-Channel TVS Diode Array**

 ESD / transient protection of data and power lines

in 3.3 V / 5 V application according to:

IEC61000-4-2 (ESD): ± 30 KV (contact)

IEC61000-4-4 (EFT): 80 A (5/50 ns)

IEC61000-4-5 (Surge): 10 A (8/20 μs)

- Working voltage: 5 V (5.3 V max.)
- Low clamping voltage
- Low reverse current < 5 μA
- Pb-free (RoHS compliant) package

#### **Applications**

- Uni or bi-directional operation possible (see application example page 5)
- Mobile communication
- Consumer products (STB, MP3, DVD, DSC...)
- LCD displays, camera
- Notebooks and desktop computers, peripherals



#### ESD5V0S4US

#### ESD5V0S5US

## ESD5V0S5US E6727 180° rotated in reel





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Туре	Package	Configuration	Marking
ESD5V0S4US	SOT363	4 lines, uni-directional	E4s
ESD5V0S5US	SOT363	5 lines, uni-directional	E5s
ESD5V3S5US E6727*	SOT363	5 lines, uni-directional	on request

<sup>\*</sup> Preliminary data



**Maximum Ratings** at  $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Value	Unit
ESD contact discharge per diode <sup>1)</sup>	V <sub>ESD</sub>	30	kV
Peak pulse current ( $t_p = 8 / 20 \mu s$ ) per diode <sup>2</sup> )	I <sub>pp</sub>	10	А
Peak pulse power ( $t_p$ = 8 / 20 $\mu$ s) per diode	$P_{pk}$	130	W
Operating temperature range	$T_{op}$	-55125	°C
Storage temperature	T <sub>stg</sub>	-65150	

**Electrical Characteristics** at  $T_A = 25$ °C, unless otherwise specified

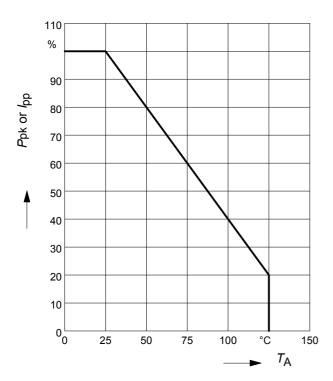
Parameter	Symbol	Values			Unit
		min.	typ.	max.	
Characteristics -		•		•	
Reverse working voltage	$V_{RWM}$	_	5	5.3	V
Breakdown voltage	V <sub>(BR)</sub>	5.7	6.7	7.7	
$I_{(BR)} = 1 \text{ mA}$	, ,				
Reverse current	I <sub>R</sub>				μA
$V_{R} = 3.3 \text{ V}$		-	-	1	
V <sub>R</sub> = 5 V		_	-	5	
Clamping voltage (positive transients)	$V_{CL}$				V
$I_{PP} = 1 \text{ A}, t_p = 8/20 \ \mu\text{s}^{2}$		-	7	9	
$I_{PP} = 10 \text{ A}, t_p = 8/20  \mu\text{s}^2)$			10.5	13	
Forward clamping voltage (negative transients)	V <sub>FC</sub>				
$I_{PP} = 1 \text{ A}, t_p = 8/20 \ \mu\text{s}^{2}$		_	1	3	
$I_{PP} = 10 \text{ A}, t_p = 8/20  \mu\text{s}^{2})$			3.5	6	
Diode capacitance	C <sub>T</sub>				pF
$V_{R} = 0 \text{ V}, f = 1 \text{ MHz}$		_	70	90	
$V_{R} = 5 \text{ V}, f = 1 \text{ MHz}$		_	35	55	

 $<sup>^{1}</sup>V_{\mathrm{ESD}}$  according to IEC61000-4-2

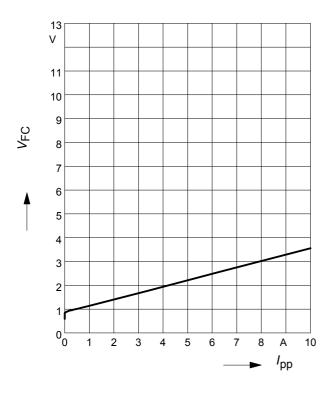
 $<sup>^2</sup>I_{pp}$  according to IEC61000-4-5



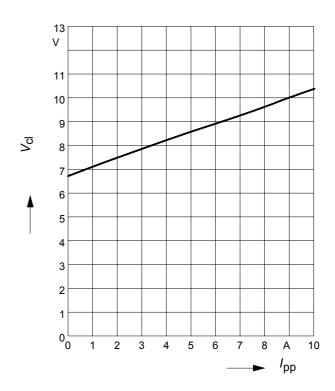
# Power derating curve $P_{pk} = f(T_A)$



Forward clamping voltage  $V_{FC}$  = f ( $I_{pp}$ )  $t_p$  = 8 / 20 µs (negative transients)

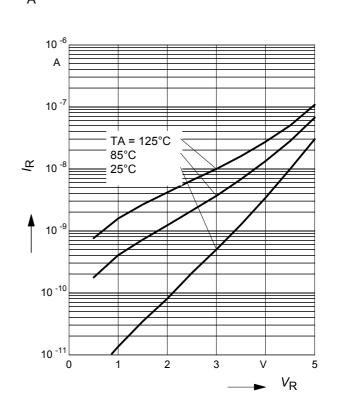


# Clamping voltage, $V_{cl} = f(I_{pp})$ $t_p = 8 / 20 \mu s$ (positive transients)



Reverse current  $I_R = f(V_R)$ 

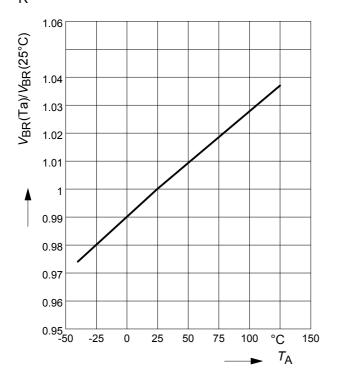
 $T_A$  = Parameter





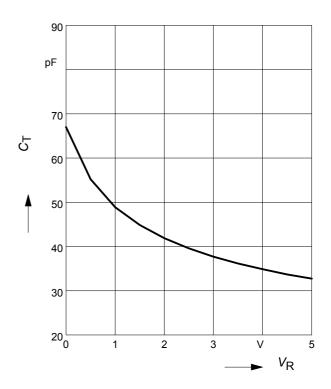
## Normalized reverse voltage

$$V_{\rm BR}(T_{\rm A})/V_{\rm BR}(25^{\circ}{\rm C}) = f(T_{\rm A})$$
  
 $I_{\rm R}=1~{\rm mA}$ 



# Diode capacitance $C_T = f(V_R)$

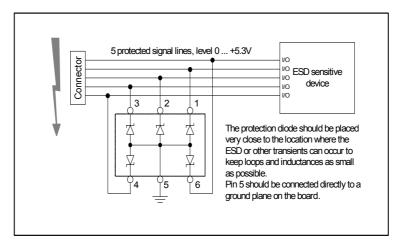
$$f = 1MHz$$





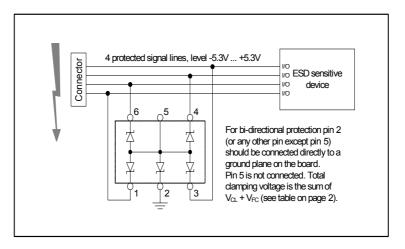
#### **Application example ESD5V0S5US**

5 channels, uni-directional



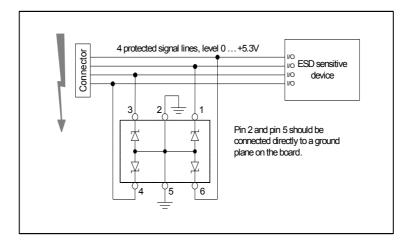
### **Application example ESD5V0S5US**

4 channels, bi-directional



## **Application example ESD5V0S4US**

4 channels, uni-directional

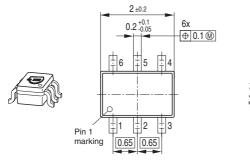


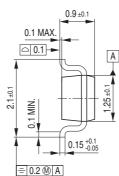
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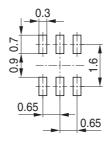


## Package Outline



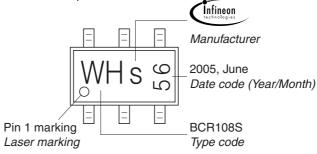


#### Foot Print



## Marking Layout (Example)

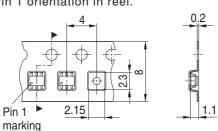
Small variations in positioning of Date code, Type code and Manufacture are possible.



# Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel

For symmetric types no defined Pin 1 orientation in reel.





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